

Data Sheet January 2000 File Number 3380.3

80A, 600V Ultrafast Diode

The RURU8060 is an ultrafast diode with soft recovery characteristics (t_{rr} < 75ns). It has low forward voltage drop and is of silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristic minimizes ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

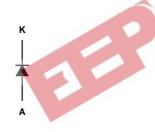
Formerly developmental type TA09886.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RURU8060	TO-218	RURU8060

NOTE: When ordering, use the entire part number.

Symbol



Features

Ultrafast with Soft Recovery	.<75ns
Operating Temperature	.175 ⁰ C
Reverse Voltage	600V

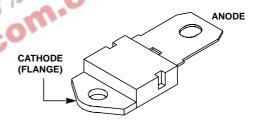
- · Avalanche Energy Rated
- · Planar Construction

Applications

- · Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC STYLE SINGLE LEAD TO-218



RURU8060

UNITS

Absolute Maximum Ratings T_C = 25°C, Unless Otherwise Specified

Peak Repetitive Reverse VoltageV _{RRM}	600	V
Working Peak Reverse Voltage	600	V
DC Blocking Voltage	600	V
Average Rectified Forward Current $I_{F(AV)}$ ($T_C = 84^{\circ}C$)	80	Α
Repetitive Peak Surge Current I _{FRM} (Square Wave, 20kHz)	160	Α
Nonrepetitive Peak Surge Current	800	Α
Maximum Power Dissipation	180	W
Avalanche Energy (See Figures 7 and 8)	50	mJ
Operating and Storage Temperature	-65 to 175	οС

RURU8060

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F	I _F = 80A	-	-	1.6	V
	$I_F = 80A, T_C = 150^{\circ}C$	-	-	1.4	V
I _R	V _R = 600V	-	-	250	μΑ
	V _R = 600V, T _C = 150 ^o C	-	-	2.0	mA
t _{rr}	I _F = 1A, dI _F /dt = 100A/μs	-	-	75	ns
	I _F = 80A, dI _F /dt = 100A/μs	-	-	85	ns
t _a	I _F = 80A, dI _F /dt = 100A/μs	-	40	-	ns
t _b	I _F = 80A, dI _F /dt = 100A/μs	-	25	-	ns
$R_{ heta JC}$		-	-	0.83	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 6), summation of t_a + t_b .

 t_a = Time to reach peak reverse current (See Figure 6).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 6). I_{RM} = Thermal resistance junction to case.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

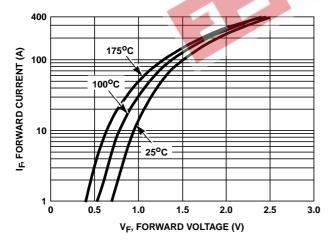


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

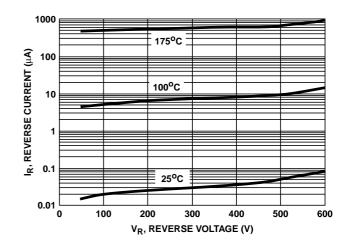
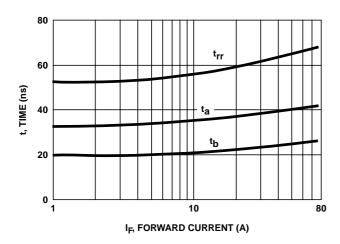


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)



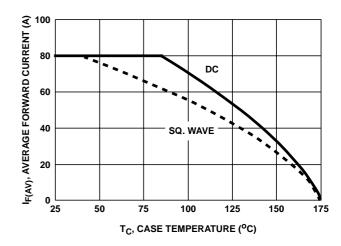


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

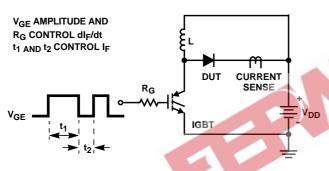


FIGURE 5. t_{rr} TEST CIRCUIT

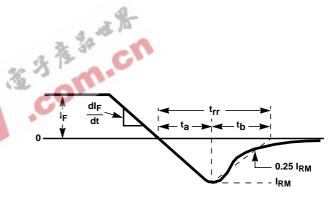


FIGURE 6. t_{rr} WAVEFORMS AND DEFINITIONS

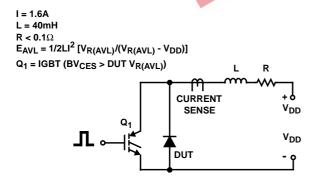


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

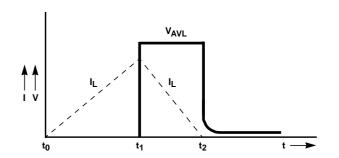


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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